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500V NPN HIGH VOLTAGE TRANSISTOR IN SOT23

Feature

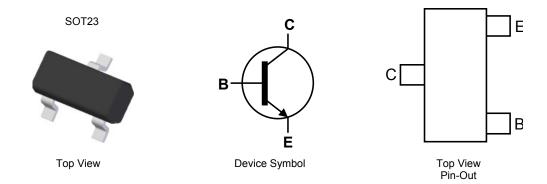
- BV_{CFV} > 500V
- BV_{ECV} > 6V reverse blocking
- I_C = 150mA high Continuous Collector Current
- I_{CM} Up to 500mA Peak Pulse Current
- 625mW Power Dissipation
- Low Saturation Voltage <-90mV @ 50mA
- Excellent hFE Characteristics Up To 120mA
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (§3)
- Weight 0.008 grams (approximate)

Applications

- Off-line switching applications
- RCD circuits
- PFC disable switch in PSU
- Emergency lighting
- Piezo actuators
- Telecom protected line switching



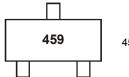
Ordering Information (Note 4)

| Part Number | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|-------------|------------|---------|--------------------|-----------------|-------------------|
| FMMT459TA | AEC-Q101 | 459 | 7 | 8 | 3,000 |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



459 = Product Type Marking Code





Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | 500 | V |
| Collector-Emitter Voltage | V _{CEV} | 500 | V |
| Collector-Emitter Voltage | V _{CEO} | 450 | V |
| Emitter-Base Voltage | V_{EBO} | 7 | V |
| Emitter-Collector Voltage | V _{ECV} | 6 | V |
| Continuous Collector Current | Ic | 150 | mA |
| Peak Pulse Current | I _{CM} | 500 | mA |
| Base Current | I _B | 200 | mA |

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|------------------|-------------|------|
| Power Dissipation (Note 5) | P _D | 625 | mW |
| Power Dissipation (Note 6) | P_{D} | 806 | mW |
| Thermal Resistance, Junction to Ambient (Note 5) | $R_{\theta JA}$ | 200 | °C/W |
| Thermal Resistance, Junction to Ambient (Note 6) | R _{0JA} | 155 | °C/W |
| Thermal Resistance, Junction to Leads (Note 7) | $R_{	heta JL}$ | 194 | °C/W |
| Operating and Storage Temperature Range | $T_{J_i}T_{STG}$ | -55 to +150 | °C |

ESD Ratings (Note 8)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | С |

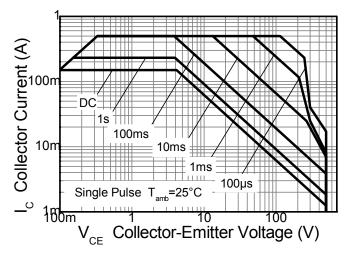
Notes:

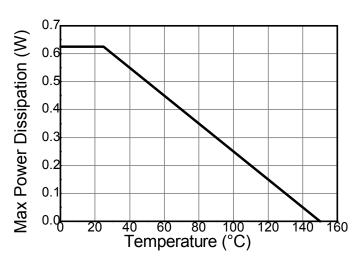
- 5. For a device mounted with the collector lead on 25mm x 25mm 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as note 5, except the device is measured at $t \le 5$ sec.
- 7. Thermal resistance from junction to solder-point (at the end of the collector lead).

 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



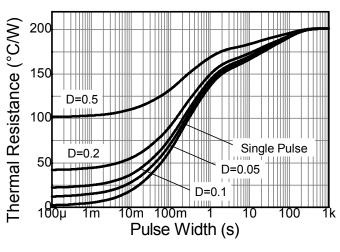
Thermal Characteristics and Derating Information

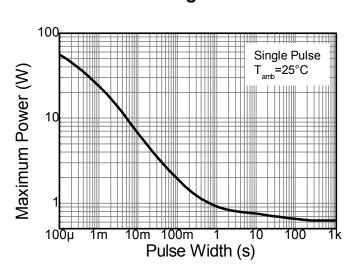




Safe Operating Area

Derating Curve





Transient Thermal Impedance

Pulse Power Dissipation





March 2014

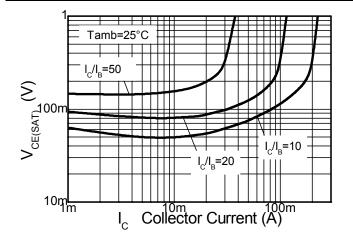
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

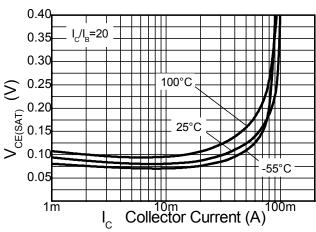
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|---|----------------------|-----|------|-----|------|--|
| Collector-Base Breakdown Voltage | BV _{CBO} | 500 | 700 | | V | I _C = 100μA |
| Collector-Emitter Breakdown Voltage | BV _{CEV} | 500 | 700 | _ | V | $I_C = 10\mu A; 0.3V > V_{BE} > -1V$ |
| Collector-Emitter Breakdown Voltage (Note 9) | BV _{CEO} | 450 | 500 | _ | V | I _C = 1mA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | 7 | 8.1 | _ | V | I _E = 100μA |
| Emitter-Base Breakdown Voltage (Reverse Blocking) | BV _{ECV} | 6 | 8.1 | _ | V | $I_C = 1\mu A; 0.3V > V_{BC} > -6V$ |
| Collector Cutoff Current | I _{CBO} | _ | <10 | 100 | nA | V _{CB} = 450V |
| Emitter Cutoff Current | I _{EBO} | _ | <10 | 100 | nA | V _{EB} = 5.6V |
| Collector Emitter Cutoff Current | I _{CES} | _ | <10 | 100 | nA | V _{CE} = 450V |
| Static Forward Current Transfer Ratio (Note 9) | h _{FE} | 50 | 120 | _ | | I _C = 30mA, V _{CE} = 10V |
| Static Folward Current Transfer Ratio (Note 9) | | _ | 70 | | | $I_C = 50 \text{mA}, V_{CE} = 10 \text{V}$ |
| Collector-Emitter Saturation Voltage (Note 9) | V _{CE(sat)} | _ | 60 | 75 | mV | $I_C = 20$ mA, $I_B = 2$ mA |
| Collector-Enritter Saturation Voltage (Note 9) | | _ | 70 | 90 | mV | I_C = 50mA, I_B = 6mA |
| Base-Emitter Turn-On Voltage (Note 9) | $V_{BE(on)}$ | _ | 0.71 | 0.9 | V | $I_C = 50 \text{mA}, V_{CE} = 10 \text{V}$ |
| Base-Emitter Saturation Voltage (Note 9) | V _{BE(sat)} | _ | 0.76 | 0.9 | V | $I_C = 50$ mA, $I_B = 5$ mA |
| Output Capacitance | C_{obo} | _ | _ | 5 | pF | V _{CB} = 20V, f = 1MHz |
| Transition Frequency | f _T | 50 | 1 | - | MHz | $V_{CE} = 20V, I_{C} = 10mA,$ f = 20MHz |
| Turn-On Time | t _{on} | _ | 113 | | ns | $V_C = 100V, I_C = 50mA$ |
| Turn-Off Time | t _{off} | _ | 3450 | _ | ns | I _{B1} = 5mA, I _{B2} = -10mA |

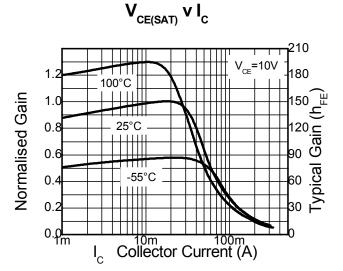
9. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

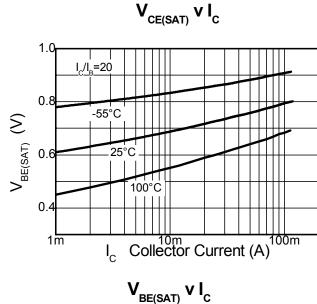


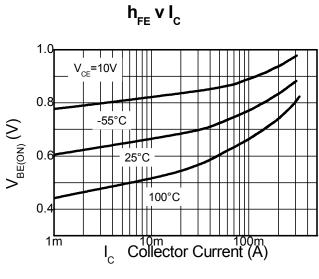
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)











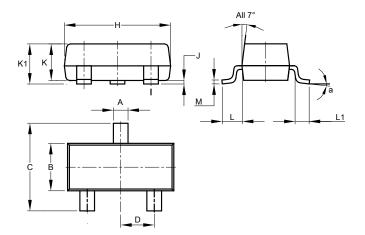


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Package Outline Dimensions

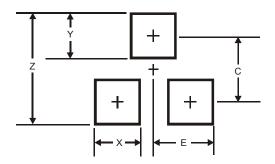
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



| SOT23 | | | | | |
|----------------------|-------|-------|-------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 0.37 | 0.51 | 0.40 | | |
| В | 1.20 | 1.40 | 1.30 | | |
| C | 2.30 | 2.50 | 2.40 | | |
| D | 0.89 | 1.03 | 0.915 | | |
| F | 0.45 | 0.60 | 0.535 | | |
| G | 1.78 | 2.05 | 1.83 | | |
| Η | 2.80 | 3.00 | 2.90 | | |
| 7 | 0.013 | 0.10 | 0.05 | | |
| K | 0.890 | 1.00 | 0.975 | | |
| K1 | 0.903 | 1.10 | 1.025 | | |
| L | 0.45 | 0.61 | 0.55 | | |
| L1 | 0.25 | 0.55 | 0.40 | | |
| М | 0.085 | 0.150 | 0.110 | | |
| а | a 8° | | | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.9 |
| Х | 8.0 |
| Υ | 0.9 |
| С | 2.0 |
| Е | 1.35 |

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.





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